

# MJE4343 (NPN), MJE4353 (PNP)

## High-Voltage - High Power Transistors

... designed for use in high power audio amplifier applications and high voltage switching regulator circuits.

### Features

- High Collector–Emitter Sustaining Voltage –  
NPN PNP  
 $V_{CEO(sus)} = 160 \text{ Vdc}$  – MJE4343 MJE4353
- High DC Current Gain – @  $I_C = 8.0 \text{ Adc}$   $h_{FE} = 35$  (Typ)
- Low Collector–Emitter Saturation Voltage –  
 $V_{CE(sat)} = 2.0 \text{ Vdc (Max) @ } I_C = 8.0 \text{ Adc}$
- These are Pb–Free Devices

### MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	$V_{CEO}$	160	Vdc
Collector–Base Voltage	$V_{CB}$	160	Vdc
Emitter–Base Voltage	$V_{EB}$	7.0	Vdc
Collector Current – Continuous Peak (Note 1)	$I_C$	16 20	Adc
Base Current – Continuous	$I_B$	5.0	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	$P_D$	125	Watts
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	–65 to +150	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.0	$^\circ\text{C/W}$

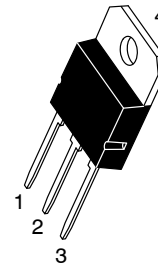
1. Pulse Test: Pulse Width  $\leq 5.0 \mu\text{s}$ , Duty Cycle  $\geq 10\%$ .



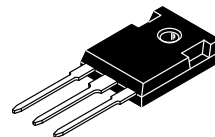
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POWER TRANSISTORS  
COMPLEMENTARY  
SILICON  
160 VOLTS**



SOT-93  
CASE 340D  
STYLE 1



TO-247  
CASE 340L  
STYLE 3

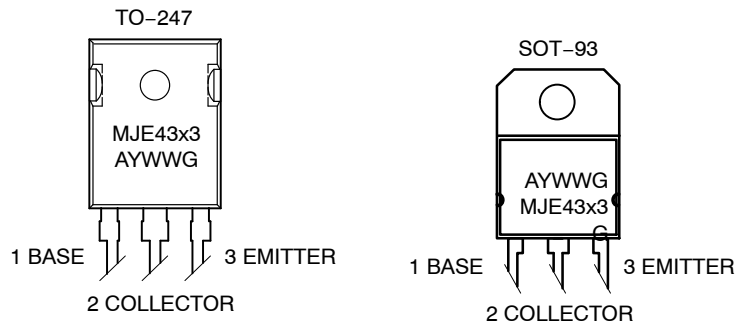
**NOTE: Effective June 2012 this device will be available only in the TO-247 package. Reference FPCN# 16827.**

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# MJE4343 (NPN), MJE4353 (PNP)

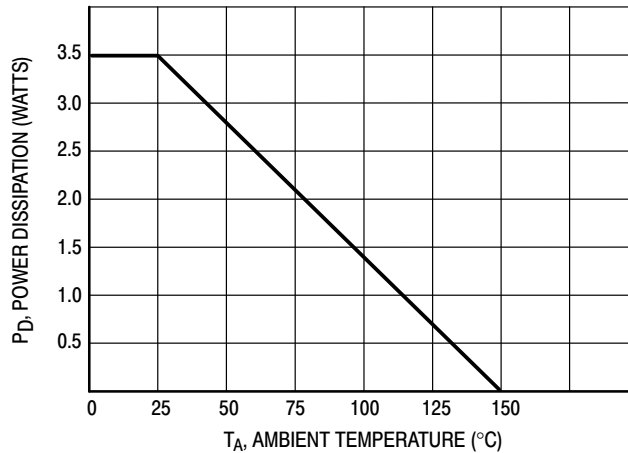
## MARKING DIAGRAMS



MJE43x3 = Device Code  
 A = Assembly Location  
 Y = Year  
 WW = Work Week  
 G = Pb-Free Package

## ORDERING INFORMATION

Device Order Number	Package Type	Shipping
MJE4343G	SOT-93 (Pb-Free)	30 Units / Rail
MJE4353G	SOT-93 (Pb-Free)	30 Units / Rail
MJE4343G	TO-247 (Pb-Free)	30 Units / Rail
MJE4353G	TO-247 (Pb-Free)	30 Units / Rail



**Figure 1. Power Derating**  
 Reference: Ambient Temperature

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### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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#### OFF CHARACTERISTICS

Collector–Emitter Sustaining Voltage (Note 2) ( $I_C = 200\text{ mA}$ , $I_B = 0$ )	$V_{CEO(sus)}$	160	–	Vdc
Collector–Emitter Cutoff Current ( $V_{CE} = 80\text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	–	750	$\mu\text{Adc}$
Collector–Emitter Cutoff Current ( $V_{CE} = \text{Rated } V_{CB}$ , $V_{EB(off)} = 1.5\text{ Vdc}$ ) ( $V_{CE} = \text{Rated } V_{CB}$ , $V_{EB(off)} = 1.5\text{ Vdc}$ , $T_C = 150^\circ\text{C}$ )	$I_{CEX}$	– –	1.0 5.0	mA
Collector–Base Cutoff Current ( $V_{CB} = \text{Rated } V_{CB}$ , $I_E = 0$ )	$I_{CBO}$	–	750	$\mu\text{Adc}$
Emitter–Base Cutoff Current ( $V_{BE} = 7.0\text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	–	1.0	mA

#### ON CHARACTERISTICS (Note 2)

DC Current Gain ( $I_C = 8.0\text{ Adc}$ , $V_{CE} = 2.0\text{ Vdc}$ ) ( $I_C = 16\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )	$h_{FE}$	15 8.0	35 (Typ) 15 (Typ)	–
Collector–Emitter Saturation Voltage ( $I_C = 8.0\text{ Adc}$ , $I_B = 800\text{ mA}$ ) ( $I_C = 16\text{ Adc}$ , $I_B = 2.0\text{ Adc}$ )	$V_{CE(sat)}$	– –	2.0 3.5	Vdc
Base–Emitter Saturation Voltage ( $I_C = 16\text{ Adc}$ , $I_B = 2.0\text{ Adc}$ )	$V_{BE(sat)}$	–	3.9	Vdc
Base–Emitter On Voltage ( $I_C = 16\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )	$V_{BE(on)}$	–	3.9	Vdc

#### DYNAMIC CHARACTERISTICS

Current–Gain – Bandwidth Product (Note 3) ( $I_C = 1.0\text{ Adc}$ , $V_{CE} = 20\text{ Vdc}$ , $f_{test} = 0.5\text{ MHz}$ )	$f_T$	1.0	–	MHz
Output Capacitance ( $V_{CB} = 10\text{ Vdc}$ , $I_E = 0$ , $f = 0.1\text{ MHz}$ )	$C_{ob}$	–	800	pF

2. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , Duty Cycle  $\geq 2.0\%$ .

3.  $f_T = |h_{fe}| \cdot f_{test}$ .

# MJE4343 (NPN), MJE4353 (PNP)

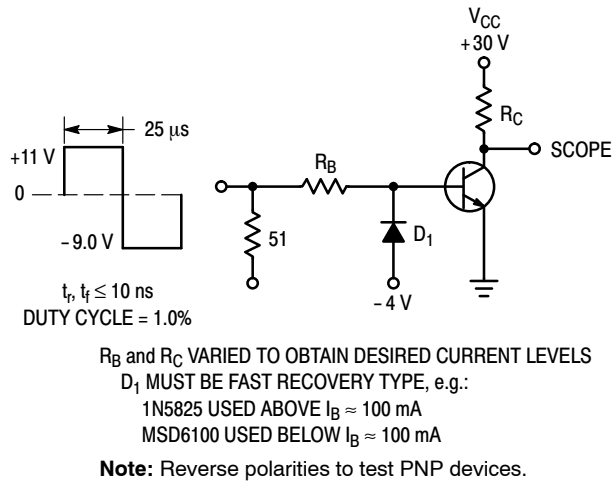


Figure 2. Switching Times Test Circuit

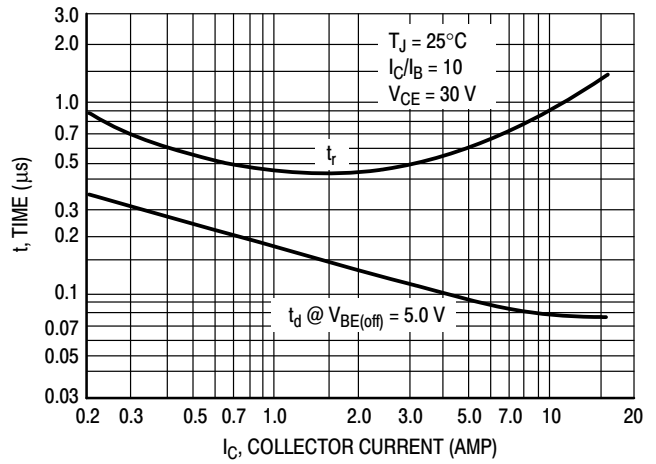


Figure 3. Typical Turn-On Time

## TYPICAL CHARACTERISTICS

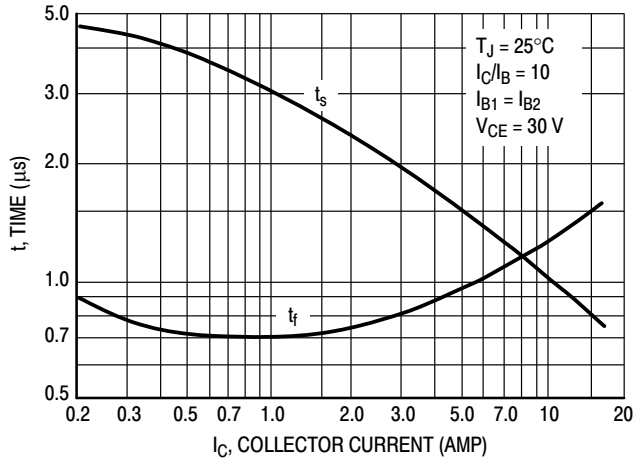


Figure 4. Turn-Off Time

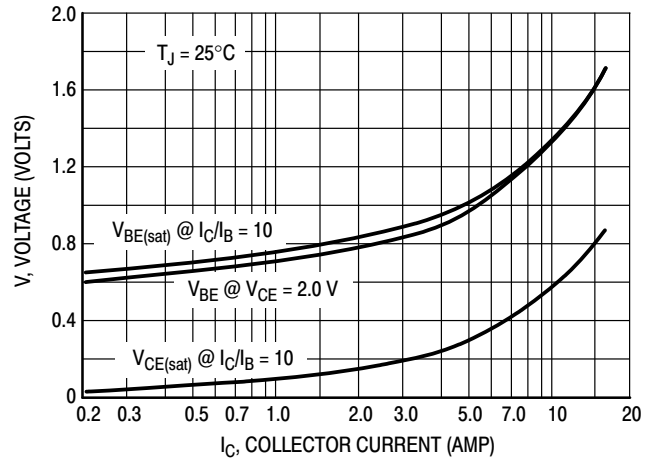


Figure 5. On Voltages

# MJE4343 (NPN), MJE4353 (PNP)

## DC CURRENT GAIN

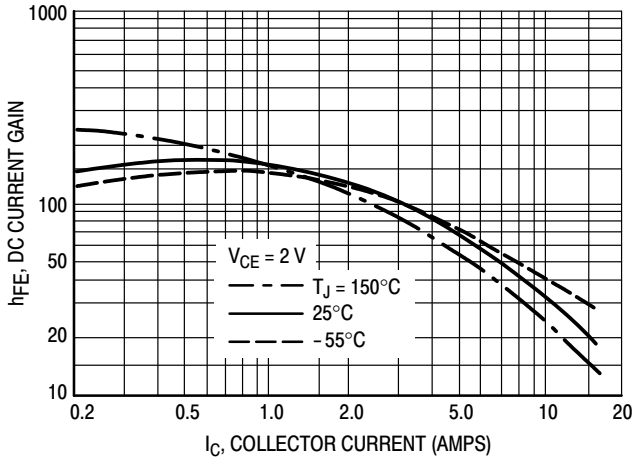


Figure 6. MJE4340 Series (NPN)

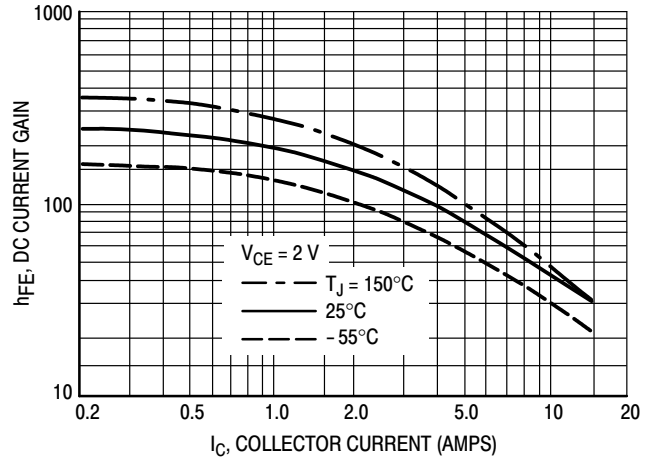


Figure 7. MJE4350 Series (PNP)

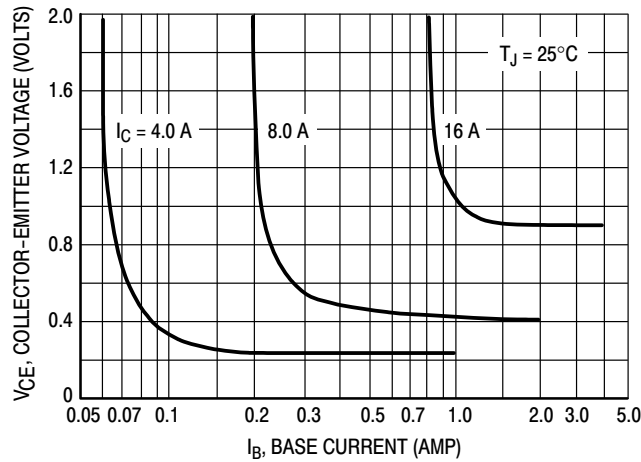


Figure 8. Collector Saturation Region

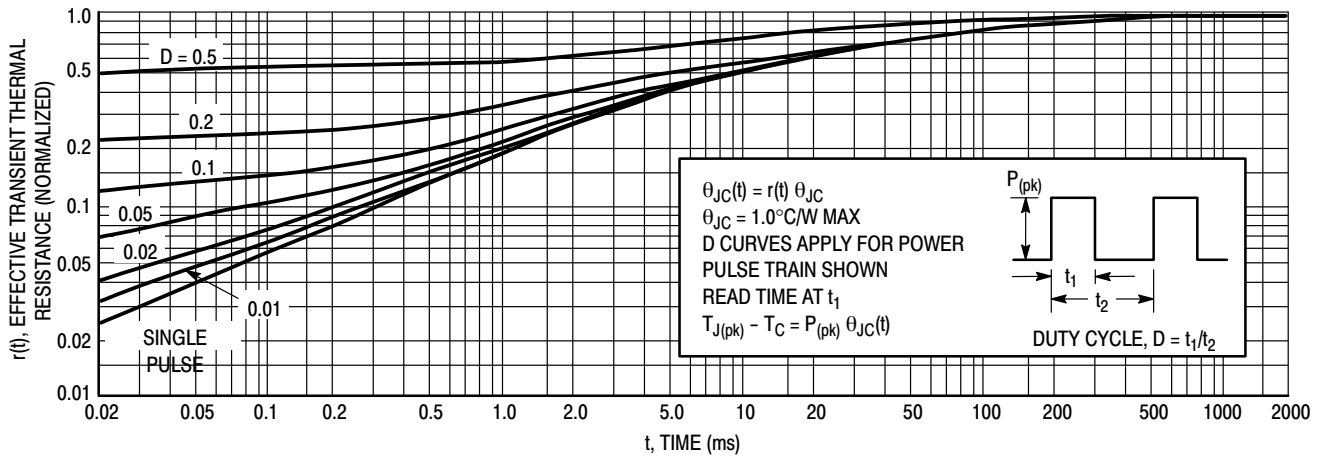
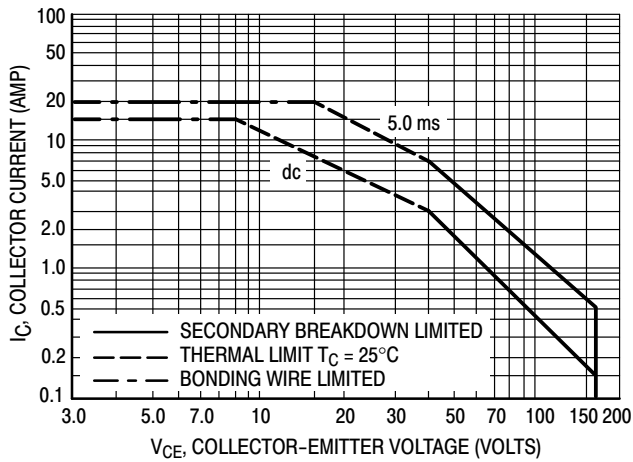


Figure 9. Thermal Response

## MJE4343 (NPN), MJE4353 (PNP)



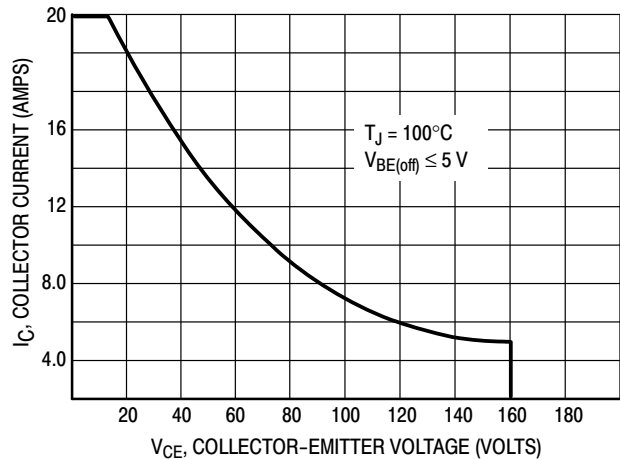
**Figure 10. Maximum Forward Bias Safe Operating Area**

### REVERSE BIAS

For inductive loads, high voltage and high current must be sustained simultaneously during turn-off, in most cases, with the base to emitter junction reverse biased. Under these conditions the collector voltage must be held to a safe level at or below a specific value of collector current. This can be accomplished by several means such as active clamping, RC snubbing, load line shaping, etc. The safe level for these devices is specified as Reverse Bias Safe Operating Area and represents the voltage-current conditions during reverse biased turn-off. This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode. Figure 11 gives RBSOA characteristics.

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 10 is based on  $T_C = 25^\circ\text{C}$ ;  $T_{J(pk)}$  is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when  $T_C \geq 25^\circ\text{C}$ . Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown on Figure 10 may be found at any case temperature by using the appropriate curve on Figure 9.

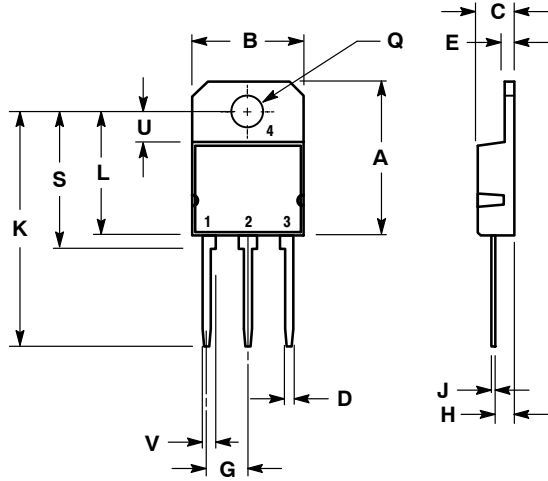


**Figure 11. Maximum Reverse Bias Safe Operating Area**

# MJE4343 (NPN), MJE4353 (PNP)

## PACKAGE DIMENSIONS

SOT-93 (TO-218)  
CASE 340D-02  
ISSUE E

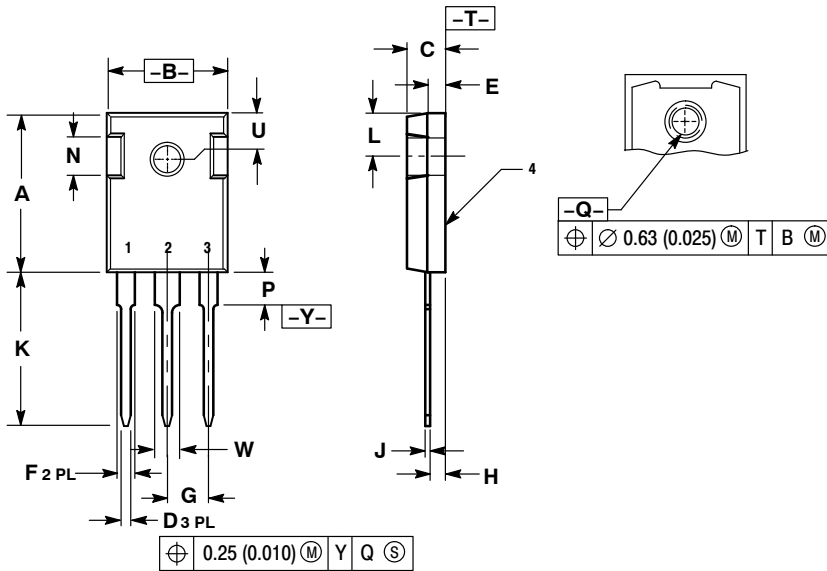


NOTES:  
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	20.35	---	0.801
B	14.70	15.20	0.579	0.598
C	4.70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
E	1.17	1.37	0.046	0.054
G	5.40	5.55	0.213	0.219
H	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L	---	16.20	---	0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157 REF	
V	1.75 REF		0.069	

STYLE 1:  
PIN 1. BASE  
2. COLLECTOR  
3. EMITTER  
4. COLLECTOR

TO-247  
CASE 340L-02  
ISSUE F




NOTES:  
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	20.32	21.08	0.800	0.830
B	15.75	16.26	0.620	0.640
C	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
E	1.90	2.60	0.075	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
H	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
K	19.81	20.83	0.780	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
P	---	4.50	---	0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242 BSC	
W	2.87	3.12	0.113	0.123

STYLE 3:  
PIN 1. BASE  
2. COLLECTOR  
3. EMITTER  
4. COLLECTOR

## MJE4343 (NPN), MJE4353 (PNP)

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